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| U.S. Department of Commerce<br>Patent and Trademark Office |  | APPLICANT<br>TAI et al.              |                                 |
| Information Disclosure Statement by Applicant              |  | FILING DATE<br>Concurrently Herewith | GROUP                           |

U.S. Patent Documents

| Examiner Initial |  | DOCUMENT NUMBER | DATE | NAME | CLASS | SUBCLASS | FILING DATE |
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Foreign Patent Documents

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|                  |  |                 |             |         |       |           | YES         | No |
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Other Documents (Including Author, Title, Date Pertinent Pages, Etc.)

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| P.L. |  | James B. Boyce et al., "Laser Crystallization for Polycrystalline Silicon Device Applications", Technology and Applications of Amorphous Silicon, R.A. Street ed. (2000), pp. 95-146    |
| P.L. |  | Akito Hara et al., "High Performance Poly-Si-TFTs on a Glass by a Stable Scanning CW Laser Lateral Crystallization", International Electron Devices Meeting (2001), pp. 747-750         |
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EXAMINER

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